

## 开关电流为 **2A** 的高输入电压降压 - 升压转换器

 查询样品: **TPS63060, TPS63061**

### 特性

- 效率高达 **93%**
- **5V** 降压模式下的输出电流为 **2A/1A**
- **5V** 升压模式 ( $V_{IN} > 4V$ ) 下的输出电流为 **1.3A**
- 降压和升压模式间的自动转换
- 典型器件静态电流少于 **30 $\mu$ A**
- 输入电压范围: **2.5V 至 12V**
- **2.5V 至 8V** 固定和可调输出电压选项
- 用于改进低输出功率时效率的省电模式
- **2.4MHz** 强制固定运行频率并可实现同步
- 电源良好输出
- 降压 - 升压交错控制™
- 关机期间负载断开
- 过温保护

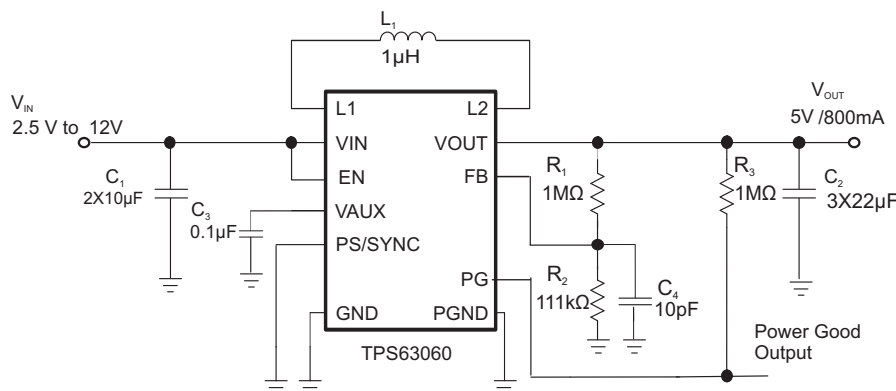
- 过压保护
- 采用 **3mm x 3mm** 小外形尺寸 (**SON**)-10 封装

### 应用范围

- 双锂离子电池应用
- 数码相机和摄像放像机
- 笔记本电脑
- 工业计量设备
- 超便携移动个人计算机和移动互联网器件
- 个人医疗产品
- 高功率 **LED**

### 说明

TPS6306x 器件为由 3 节 (最多 6 节) 碱性电池、镍镉电池 (NiCd) 或者镍氢电池 (NiMH) 电池、或者一节锂离子或者锂聚合物电池供电的产品提供了一套电源解决方案。当使用一个双锂离子或者锂聚合物电池时, 输出电流可升高至 **2A** 并将电池电压放电至 **5V** 或者更低。此降压-升压转换器基于一个使用同步整流的固定频率、脉宽调制控制器以获得最高效率。在低负载电流情况下, 此转换器进入省电模式以在宽负载电流范围内保持高效率。省电模式可被禁用, 强制转换器运行在固定的开关频率下。开关内的最大平均电流被限制在 **2.5A** (典型值)。使用一个外部电阻器分压器可对输出电压进行编程, 或者在芯片上对输出电压进行内部固定。转换器可被禁用以大大减少电池消耗。在关机期间, 负载从电池上断开。此器件封装在一个 10 引脚的小外形尺寸 (**SON**) PowerPAD 封装。™ 3mm x 3mm 封装内 (DSC)。



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

降压 - 升压交错控制, PowerPAD封装, are trademarks of Texas Instruments.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### AVAILABLE DEVICE OPTIONS<sup>(1)</sup>

T <sub>A</sub>	OUTPUT VOLTAGE DC/DC	PACKAGE MARKING	PACKAGE	PART NUMBER <sup>(2)</sup>
-40°C to 85°C	Adjustable	QUJ	10-Pin SON	TPS63060DSC
	5 V	QUK		TPS63061DSC

(1) Contact the factory to check availability of other fixed output voltage versions.

(2) For detailed ordering information please check the PACKAGE OPTION ADDENDUM section at the end of this data sheet.

### ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		VALUE		UNIT
		MIN	MAX	
Voltage range	V <sub>IN</sub> , V <sub>OUT</sub> , PS/SYNC, EN, FB	-0.3	17	V
	L1, L2	-0.3	V <sub>IN</sub> +0.3	V
	FB, V <sub>AUX</sub>	-0.3	7.5	V
Operating virtual junction temperature range, T <sub>J</sub>		-40	150	°C
Storage temperature range T <sub>stg</sub>		-65	150	°C
ESD rating <sup>(2)</sup>	Human Body Model - (HBM)		3	kV
	Machine Model - (MM)		200	V
	Charge Device Model - (CDM)		1.5	kV

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) ESD testing is performed according to the respective JEDEC standard.

### THERMAL INFORMATION

THERMAL METRIC <sup>(1)</sup>		TPS63060, TPS63061	UNITS
		DSC (10 PINS)	
θ <sub>JA</sub>	Junction-to-ambient thermal resistance	48.7	°C/W
θ <sub>JC(TOP)</sub>	Junction-to-case(top) thermal resistance	54.8	
θ <sub>JB</sub>	Junction-to-board thermal resistance	19.8	
ψ <sub>JT</sub>	Junction-to-top characterization parameter	1.1	
ψ <sub>JB</sub>	Junction-to-board characterization parameter	19.6	
θ <sub>JC(BOTTOM)</sub>	Junction-to-case(bottom) thermal resistance	4.2	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

### RECOMMENDED OPERATING CONDITIONS

	MIN	NOM	MAX	UNIT
Supply voltage at V <sub>IN</sub>	2.5		12	V
Output Current I <sub>out</sub> with V <sub>IN</sub> = 10V to 12V			1	A
Operating free air temperature range, T <sub>A</sub>	-40		85	°C
Operating virtual junction temperature range, T <sub>J</sub> Output Current I <sub>out</sub>	-40		125	°C

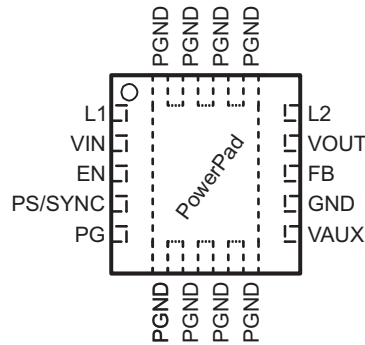
## ELECTRICAL CHARACTERISTICS

over recommended free-air temperature range and over recommended input voltage range (typical at an ambient temperature range of 25°C) (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
<b>DC/DC STAGE</b>							
$V_{IN}$	Input voltage range		2.5		12	V	
$V_{IIN}$	Minimum input voltage for startup				2.5	V	
$V_{OUT}$	TPS63060 output voltage range		2.5		8	V	
	Minimum duty cycle in step down conversion			10%	20%		
$V_{FB}$	TPS63060 feedback voltage	PS/SYNC = $V_{IN}$	495	500	505	mV	
	TPS63061 output voltage		4.95	5.0	5.05	V	
$V_{FB}$	TPS63060 feedback voltage	PS/SYNC = GND Referenced to 500mV	0.6%		5%		
	TPS63061 output voltage	PS/SYNC = GND Referenced to 5V	0.6%		5%		
f	Oscillator frequency		2200	2400	2600	kHz	
	Frequency range for synchronization		2200	2400	2600	kHz	
$I_{SW}$	Average inductance current limit	$V_{IN} = 5V, T_A = 25^\circ C$	2000	2250	2500	mA	
	High side switch on resistance	$V_{IN} = 5V$		90		m $\Omega$	
	Low side switch on resistance	$V_{IN} = 5V$		95		m $\Omega$	
	Line regulation	Power Save Mode disabled		0.5%			
	Load regulation	Power Save Mode disabled		0.5%			
$I_q$	Quiescent current	$V_{IN}$	$I_O = 0\text{ mA}, V_{EN} = V_{IN} = 5V,$ $V_{OUT} = 5V$		30	60	$\mu A$
		$V_{OUT}$			7	15	$\mu A$
	TPS63061 FB input impedance	$V_{EN} = \text{HIGH}$		1.5		M $\Omega$	
$I_S$	Shutdown current	$V_{EN} = 0\text{ V}, V_{IN} = 5V$		0.3	2	$\mu A$	
<b>CONTROL STAGE</b>							
$V_{AUX}$	Maximum bias voltage	$V_{IN} > V_{OUT}$	$V_{IN}$		7	V	
		$V_{IN} < V_{OUT}$	$V_{OUT}$		7	V	
$I_{AUX}$	Load current at $V_{AUX}$				1	mA	
UVLO	Under voltage lockout threshold	$V_{IN}$ voltage decreasing	1.8	1.9	2.2	V	
	UVLO hysteresis			300		mV	
$V_{IL}$	EN, PS/SYNC input low voltage				0.4	V	
$V_{IH}$	EN, PS/SYNC input high voltage		1.2			V	
	EN, PS/SYNC input current	Clamped on GND or $V_{IN}$		0.01	0.1	$\mu A$	
	PG output low voltage	$V_{OUT} = 5V, I_{PGL} = 10\ \mu A$		0.04	0.4	V	
	PG output leakage current			0.01	0.1	$\mu A$	
	Output overvoltage protection		12		16	V	
	Overtemperature protection			140		$^\circ C$	
	Overtemperature hysteresis			20		$^\circ C$	

## PIN ASSIGNMENTS

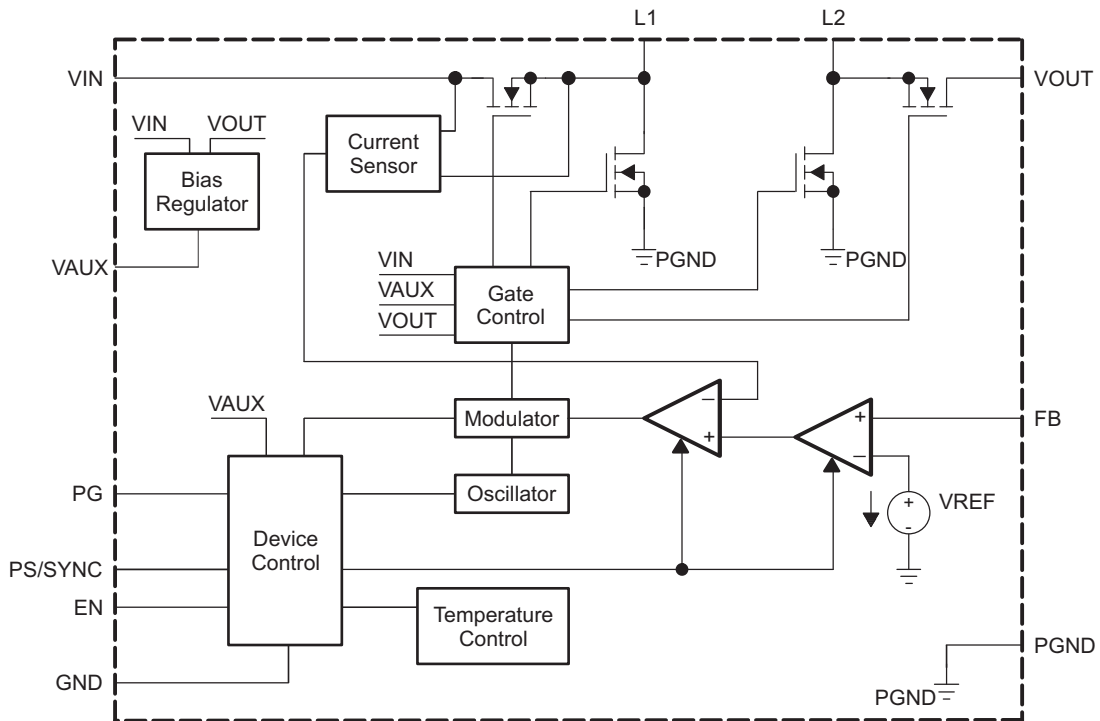
DSC PACKAGE  
(TOP VIEW)



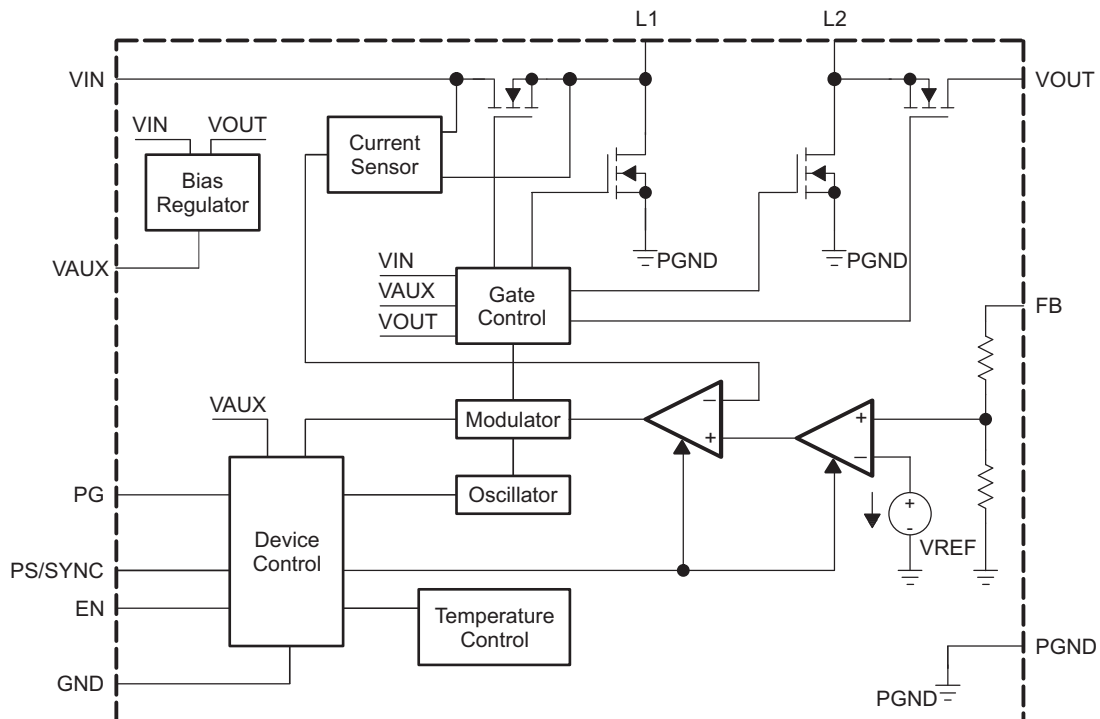
### Pin Functions

NAME	PIN NO.	I/O	DESCRIPTION
EN	3	I	Enable input. (1 enabled, 0 disabled)
FB	8	I	Voltage feedback of adjustable versions, must be connected to VOUT on fixed output voltage versions
GND	7		Control / logic ground
L1	1	I	Connection for Inductor
L2	10	I	Connection for Inductor
PS/SYNC	4	I	Enable / disable power save mode (1 disabled, 0 enabled, clock signal for synchronization)
PG	5	O	Output power good (1 good, 0 failure; open drain)
PGND	PowerPAD™		Power ground
VIN	2	I	Supply voltage for power stage
VOUT	9	O	Buck-boost converter output
VAUX	6		Connection for Capacitor
PowerPAD™			Must be soldered to achieve appropriate power dissipation. Must be connected to PGND.

FUNCTIONAL BLOCK DIAGRAM (TPS63060)



FUNCTIONAL BLOCK DIAGRAM (TPS63061)



## TYPICAL CHARACTERISTICS

### TABLE OF GRAPHS

DESCRIPTION		FIGURE	
Maximum output current	vs Input voltage (TPS63060, VOUT = 2.5 V / VOUT = 8 V)	1	
	vs Input voltage (TPS63061, VOUT = 5V)	2	
Efficiency	vs Output current (TPS63060, Power Save Enabled, VOUT = 2.5 V / VOUT = 8 V)	3	
	vs Output current (TPS63060, Power Save Disabled, VOUT = 2.5 V / VOUT = 8V)	4	
	vs Output current (TPS63061, Power Save Disabled, VOUT = 5V)	5	
	vs Output current (TPS63061, Power Save Enabled, VOUT = 5V)	6	
	vs Input voltage (TPS63060, Power Save Enabled, VOUT = 2.5V, IOU = {10; 500; 1000; 1300 mA})	7	
	vs Input voltage (TPS63060, Power Save Disabled, VOUT = 2.5V, IOU = {10; 500; 1000; 1300 mA})	8	
	vs Input voltage (TPS63060, Power Save Enabled, VOUT = 8V, IOU = {10; 500; 1000; 1300 mA})	9	
	vs Input voltage (TPS63060, Power Save Disabled, VOUT = 8V, IOU = {10; 500; 1000; 1300 mA})	10	
	vs Input voltage (TPS63061, Power Save Enabled, VOUT = 5V, IOU = {10; 500; 1000; 1300 mA})	11	
	vs Input voltage (TPS63061, Power Save Disabled, VOUT = 5V, IOU = {10; 500; 1000; 1300 mA})	12	
	Output voltage	vs Output current (TPS63060, VOUT = 2.5 V)	13
		vs Output current (TPS63061, VOUT = 5V)	14
vs Output current (TPS63060, VOUT = 8V)		15	
Waveforms	Load Transient response ( TPS63061, Vin<Vout, Load Change from 600mA to 1A)	16	
	Load Transient response (TPS63061, Vin>Vout, Load change from 600mA to 1A)	17	
	Line Transient response (TPS63061, Vout=5V, Iout=500mA)	18	
	Startup after enable (TPS63061, Vout=5V, Vin=4.5V, Iout=1A)	19	
	Start up after enable ( TPS63061, Vout=5V, Vin=8V, Iout=2A)	20	
	Load Transient response (TPS63060, Vin<Vout, Load change from 600mA to 1A)	21	
	Load Transient response, (TPS63060, Vin>Vout, Load change from 600mA to 1A)	22	
	Line Transient response (TPS63060, Vout=8V, Iout=500mA)	23	
	Start up after enable (TPS63060, Vout=8V, Vin< Vout, Vin=5V, Iout=1A)	24	
	Startup after enable (TPS63060, Vout=8V, Vin=12V, Iout=1A)	25	
	Shutdown Current versus Input Voltage	26	
	Quiescent Current versus Input Voltage	27	

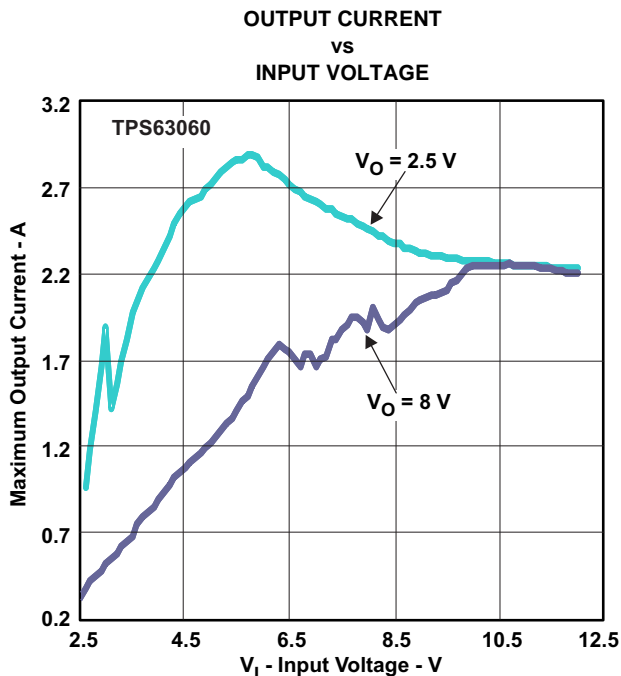


Figure 1.

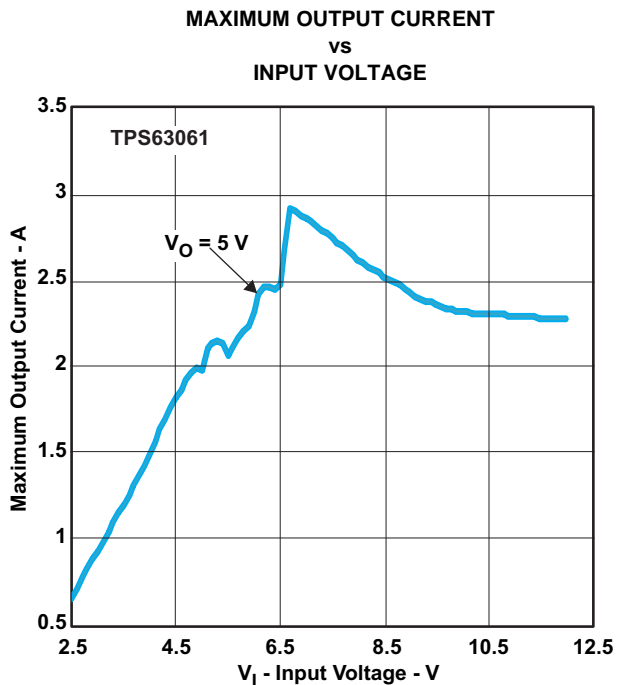


Figure 2.

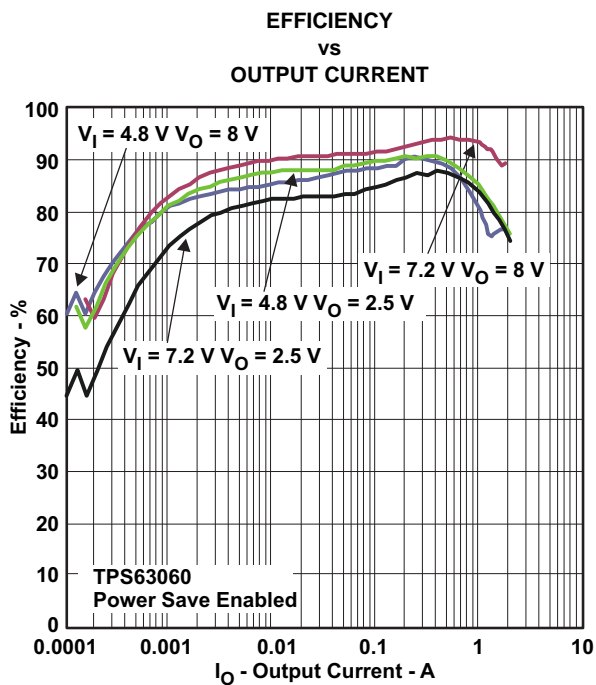


Figure 3.

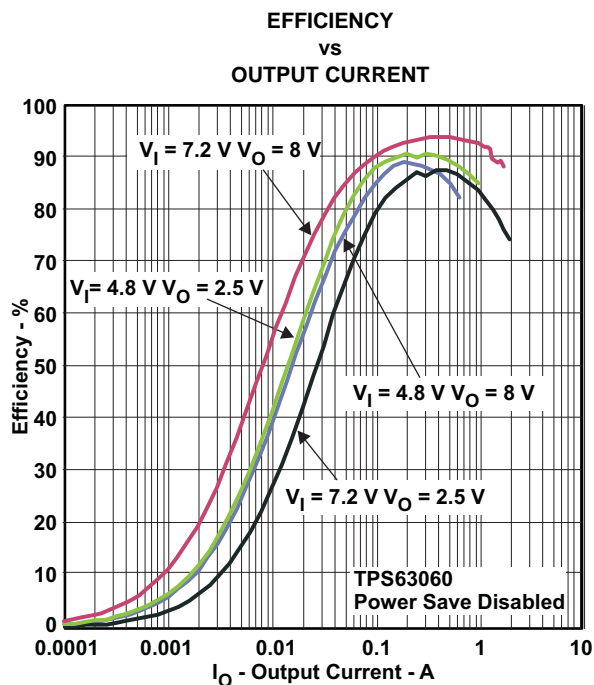
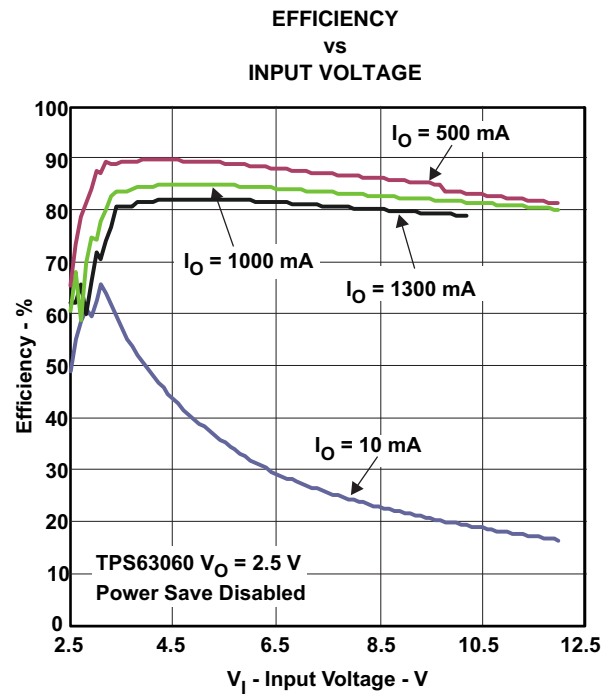
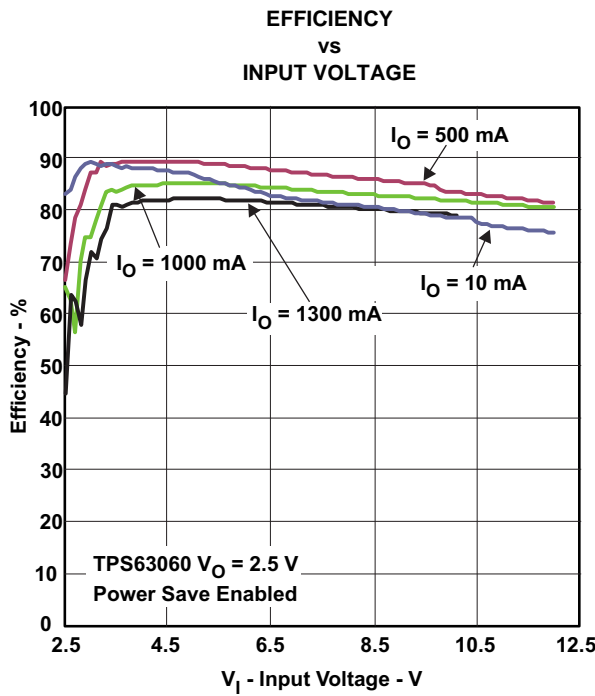
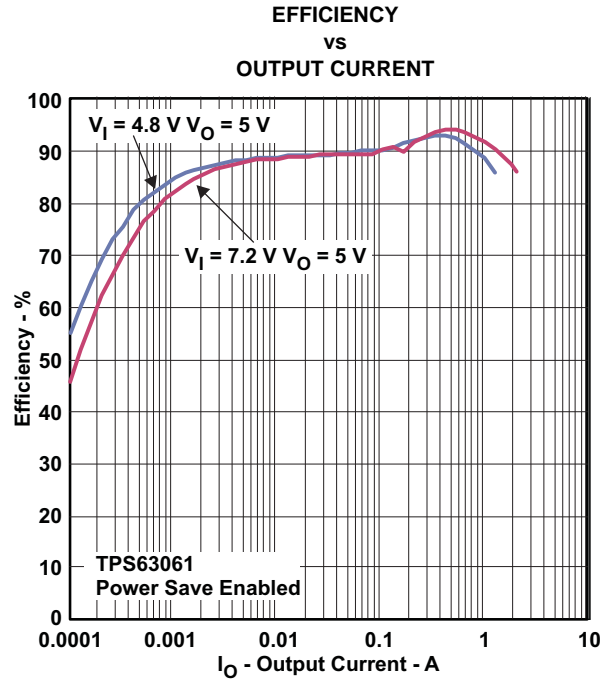
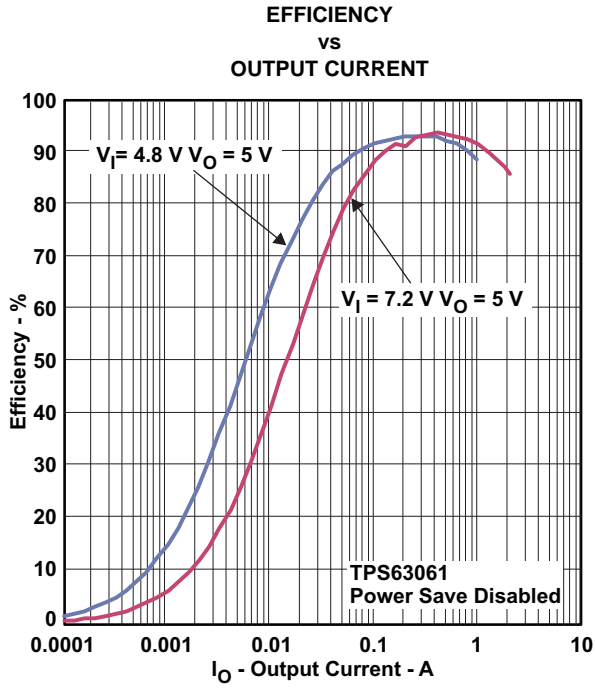


Figure 4.





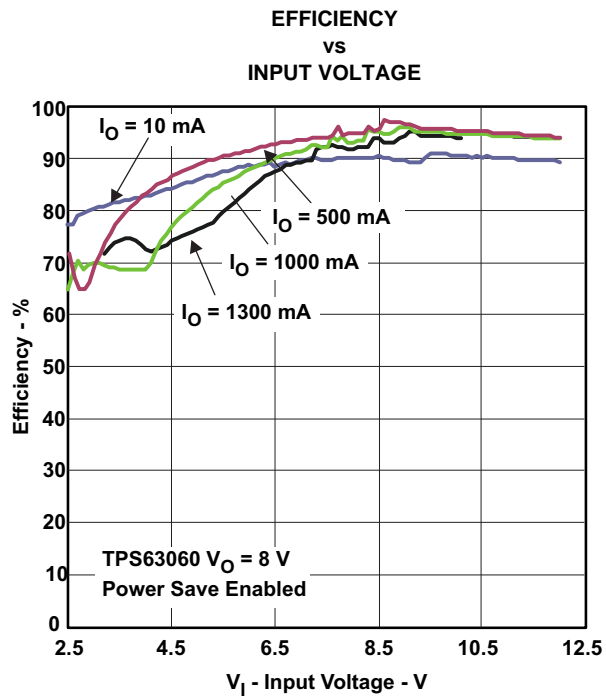


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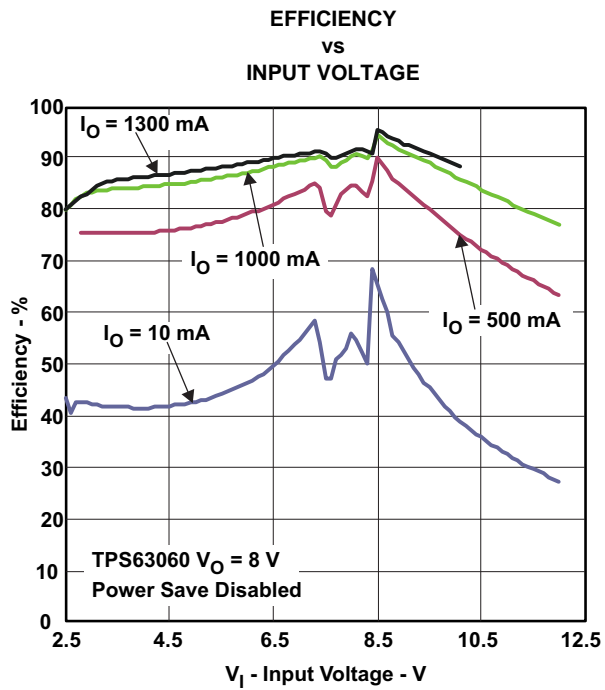


Figure 10.

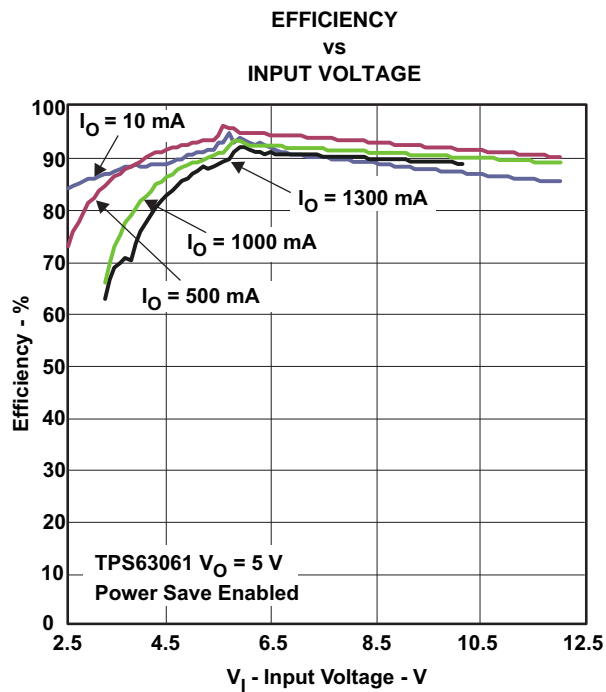


Figure 11.

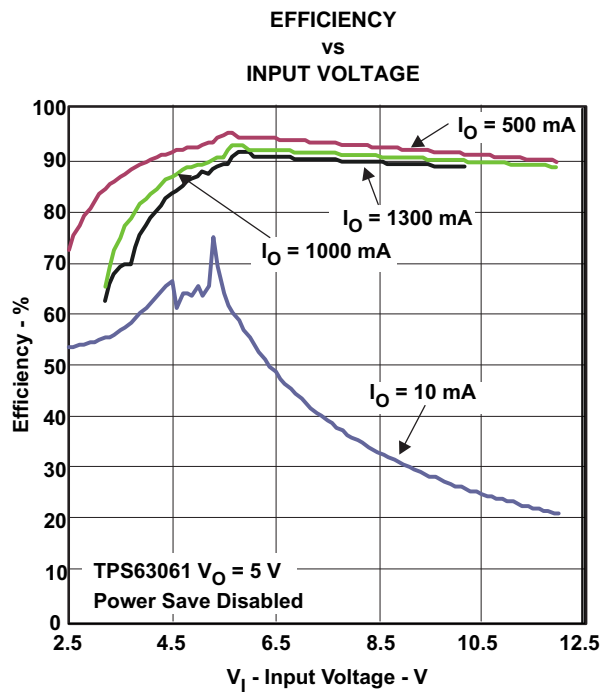
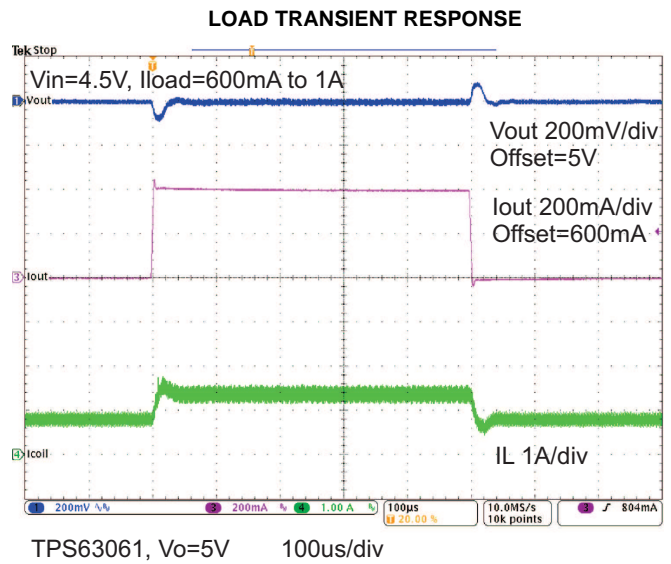
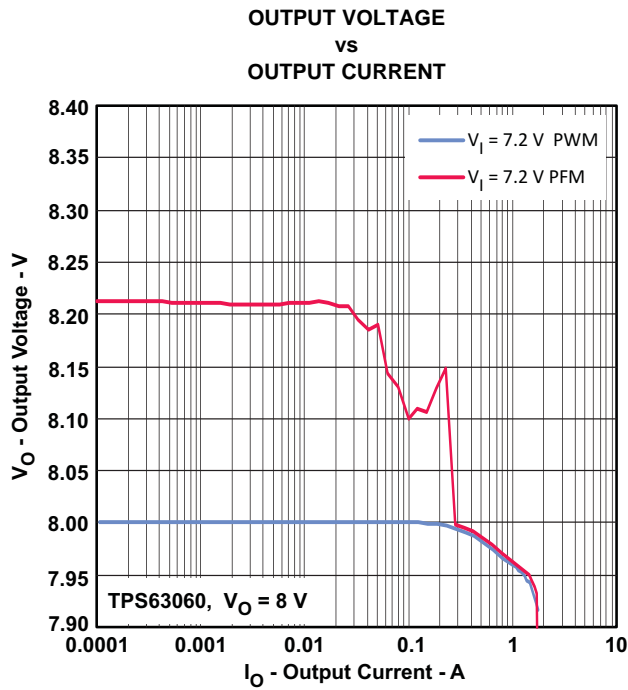
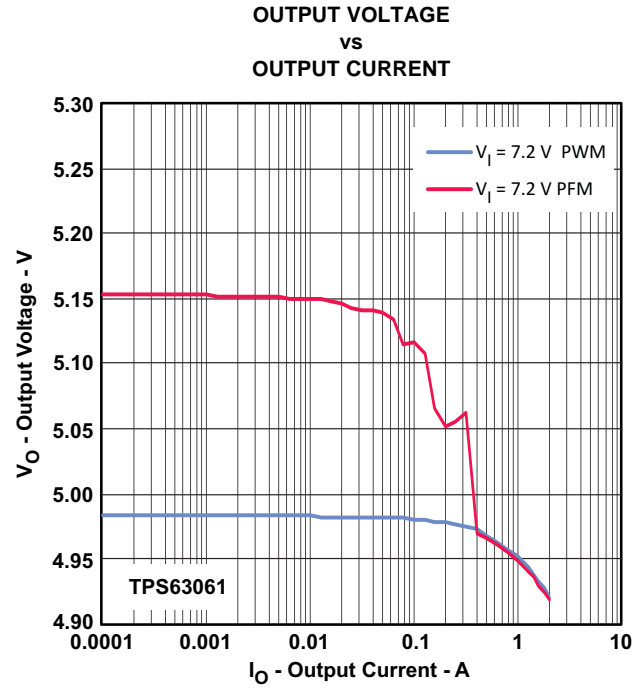
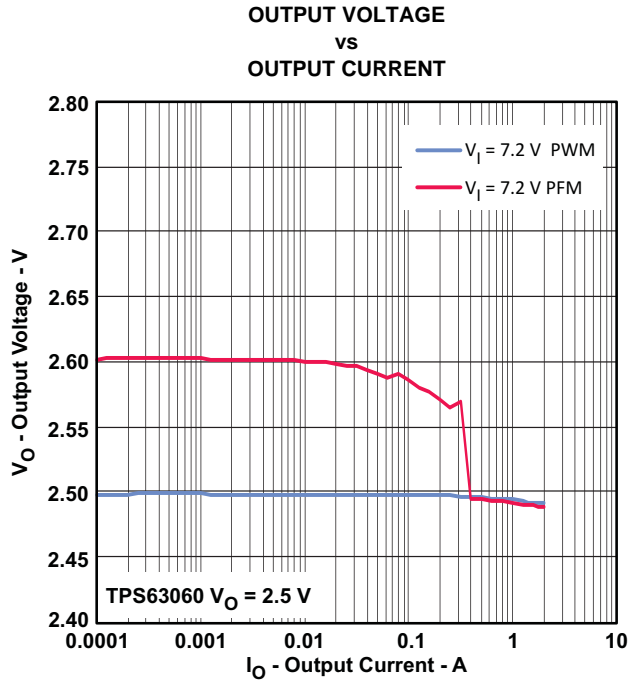
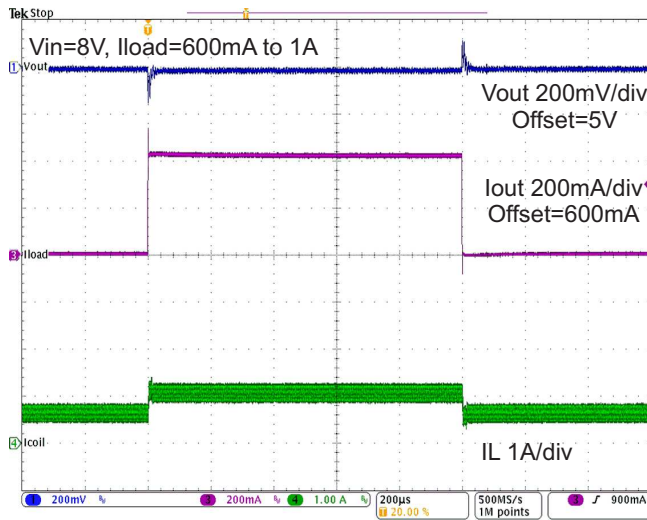


Figure 12.



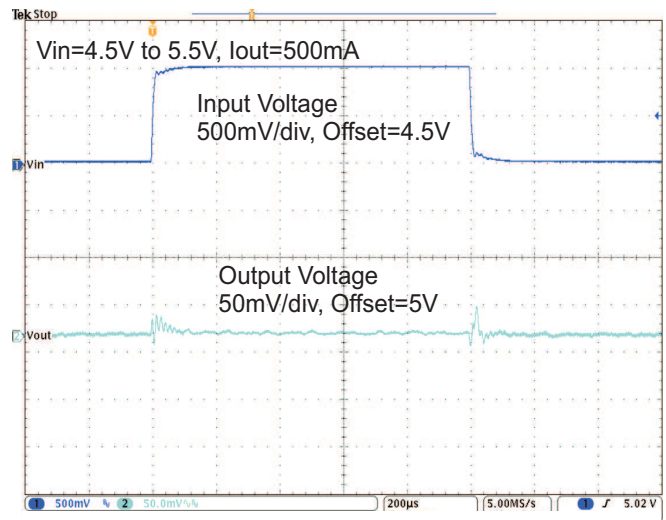
LOAD TRANSIENT RESPONSE



TPS63061, Vo=5V 200us/div

Figure 17.

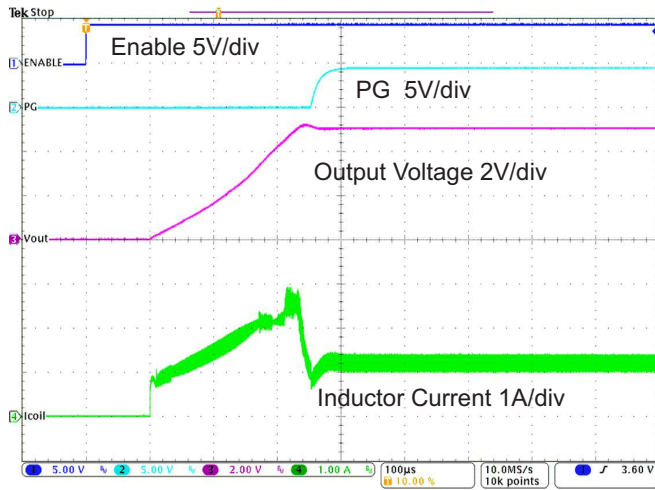
LINE TRANSIENT RESPONSE



TPS63061, Vo=5V 200us/div

Figure 18.

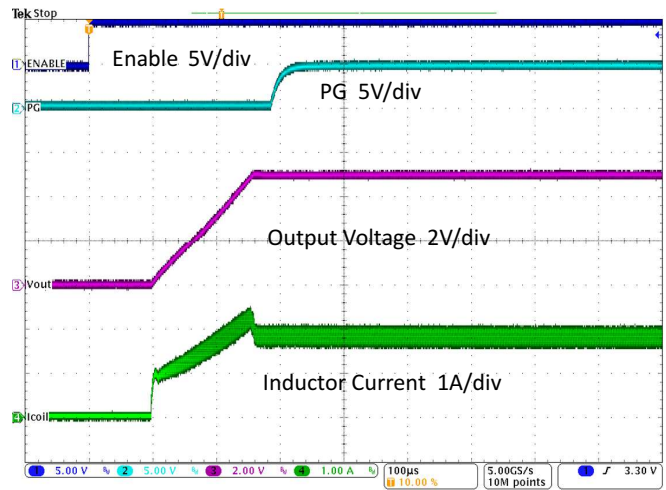
STARTUP AFTER ENABLE



TPS63061, Vo=5V 100us/div Vin=4.5V, Io=1A

Figure 19.

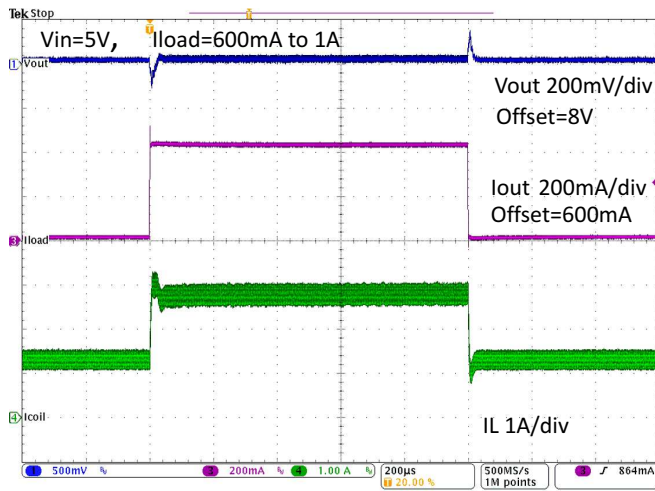
STARTUP AFTER ENABLE



TPS63061, Vo=5V 100us/div Vin=8V, Io=2A

Figure 20.

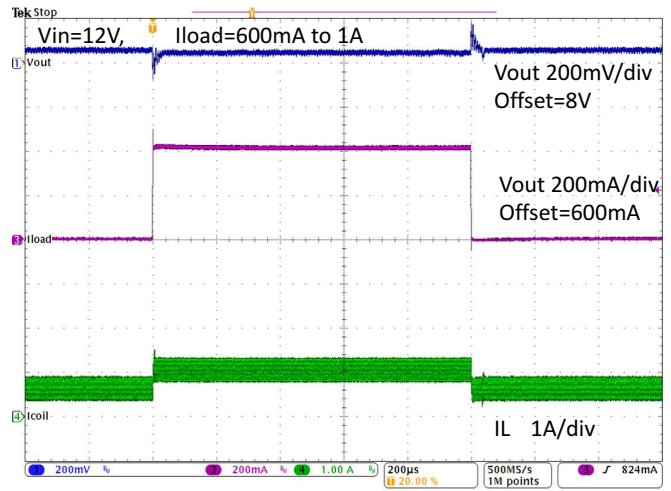
LOAD TRANSIENT



TPS63060, Vo=8V 200us/div

Figure 21.

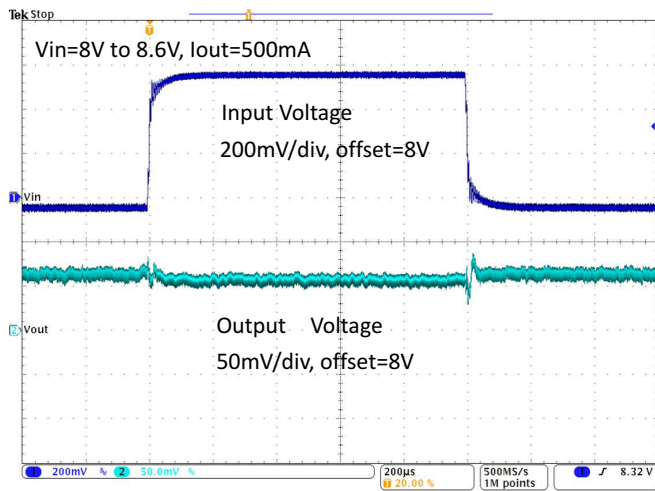
LOAD TRANSIENT



TPS63060, Vo=8V 200us/div

Figure 22.

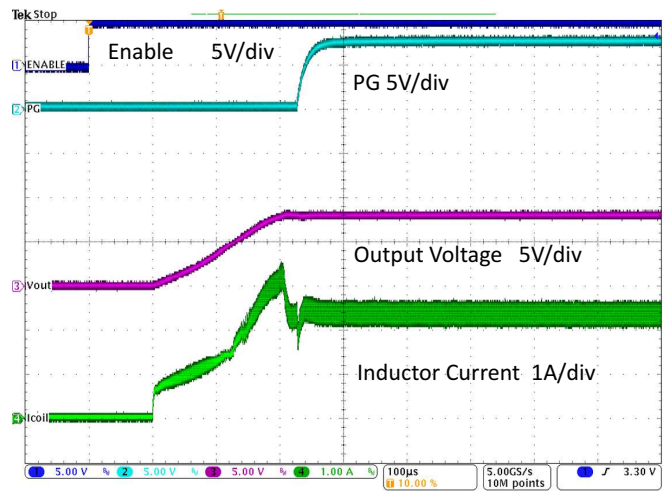
LINE TRANSIENT



TPS63060 Vo=8V 200us/div

Figure 23.

STARTUP AFTER ENABLE



TPS63060, Vo=8V 100us/div Vin=5V, Io=1A

Figure 24.

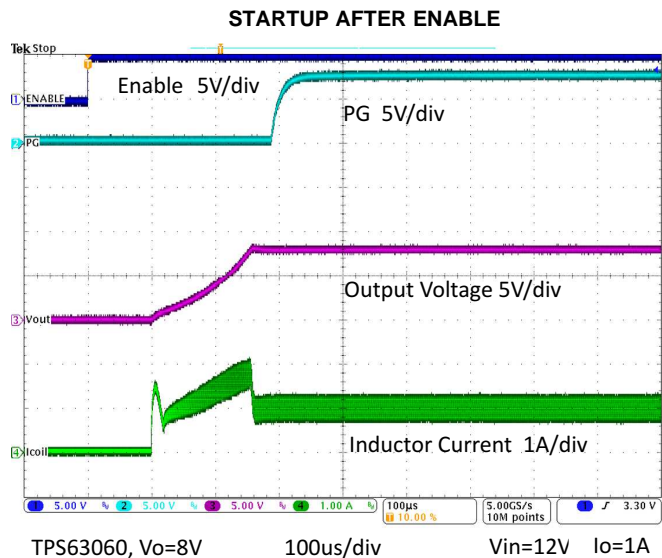


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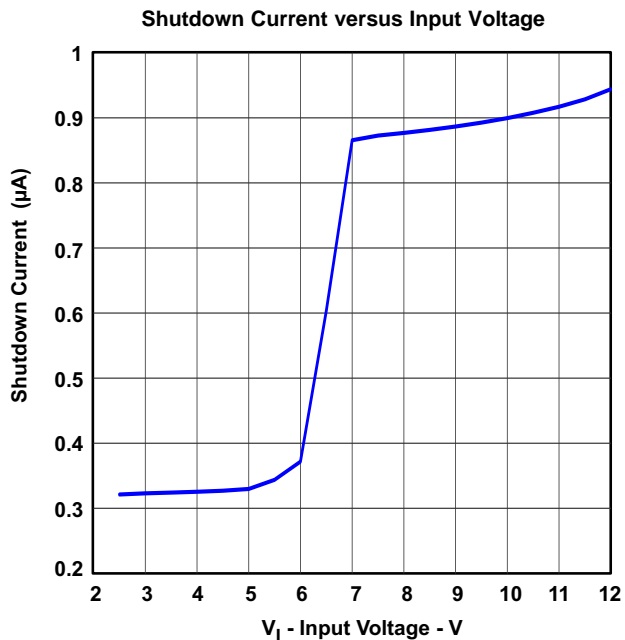


Figure 26.

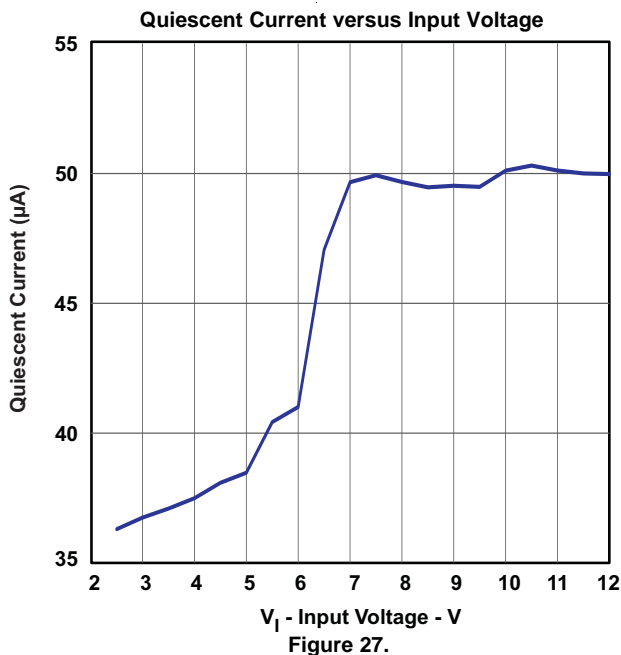
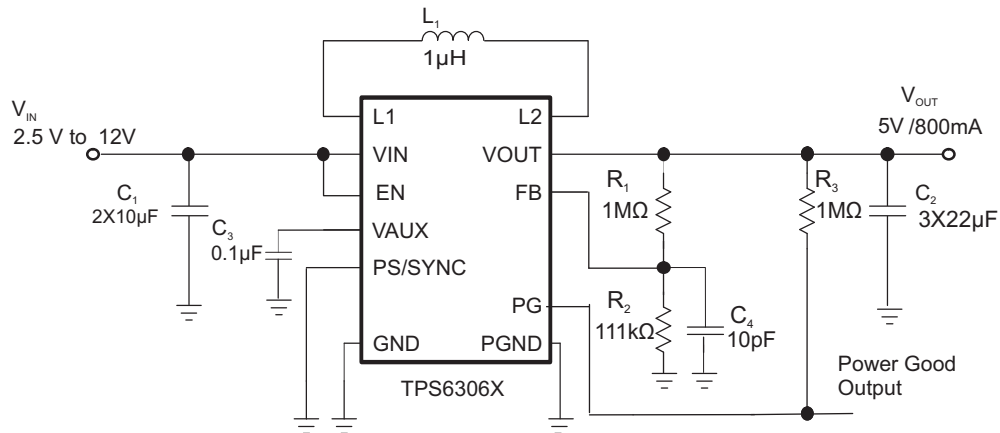


Figure 27.

**PARAMETER MEASUREMENT INFORMATION**



**Table 1. List of Components**

REFERENCE	DESCRIPTION	MANUFACTURER
	TPS63060 and TPS63061	Texas Instruments
L1	1µH, 3 mm x 3 mm x 1.5 mm	Coilcraft , XFL4020-102
C1	2 x 10 µF 16V, 0805, X5R ceramic	Taiyo Yuden, EMK212BJ
C2	3 x 22 µF 16V, 0805, X5R ceramic	Taiyo Yuden, LMK212BJ
C3	0.1 µF, X5R ceramic	
C4	10pF, ceramic	
R1, R2	Depending on the output voltage at TPS63060 and TPS63061: R1=0, C4 and R2 n.a.	

## DETAILED DESCRIPTION

### DETAILED DESCRIPTION

The controller circuit of the device is based on an average current mode topology. The controller also uses input and output voltage feedforward. Changes of input and output voltage are monitored and immediately can change the duty cycle in the modulator to achieve a fast response to those errors. The voltage error amplifier gets its feedback input from the FB pin. At adjustable output voltages, a resistive voltage divider must be connected to that pin. At fixed output voltages, FB must be connected to the output voltage to directly sense the voltage. Fixed output voltage versions use a trimmed internal resistive divider. The feedback voltage will be compared with the internal reference voltage to generate a stable and accurate output voltage.

The device uses 4 internal N-channel MOSFETs to maintain synchronous power conversion at all possible operating conditions. This enables the device to keep high efficiency over a wide input voltage and output power range. To avoid ground shift problems due to the high currents in the switches, two separate ground pins GND and PGND are used. The reference for all control functions is the GND pin. The power switches are connected to PGND. Both grounds must be connected on the PCB at only one point, ideally, close to the GND pin. Due to the 4-switch topology, the load is always disconnected from the input during shutdown of the converter. To protect the device from overheating an internal temperature sensor is implemented.

#### Buck-Boost Operation

To regulate the output voltage at all possible input voltage conditions, the device automatically switches from buck operation to boost operation and back as required. It always uses one active switch, one rectifying switch, one switch permanently on, and one switch permanently off. Therefore, it operates as a step down converter (buck) when the input voltage is higher than the output voltage, and as a boost converter when the input voltage is lower than the output voltage. There is no mode of operation in which all 4 switches are permanently switching. Controlling the switches this way allows the converter to maintain high efficiency at the most important point of operation, when the input voltage is close to the output voltage. The RMS current through the switches and the inductor is kept at a minimum, to minimize switching and conduction losses.

#### Control Loop Description

The average inductor current is regulated by a fast current regulator loop which is controlled by a voltage control loop. [Figure 28](#) shows the control loop.

The non inverting input of the transconductance amplifier  $G_{mc}$  can be assumed to be constant. The output of  $G_{mv}$  defines the average inductor current. The current through resistor  $R_S$ , which represents the actual inductor current, is compared to the desired value and the difference, or current error, is amplified and compared to the sawtooth ramp of either the Buck or the Boost.

The Buck-Boost Overlap Control™ makes sure that the classical buck-boost function, which would cause two switches to be on every half a cycle, is avoided. Thanks to this block whenever all switches becomes active during one clock cycle, the two ramps are shifted away from each other. However, when there is no switching activities because there is a gap between the ramps, the ramps are moved closer together. As a result the number of classical buck-boost cycles or no switching is reduced to a minimum and high efficiency values are achieved.

Slope compensation is not required to avoid subharmonic oscillation which are otherwise observed when working with peak current mode control with  $D > 0.5$ .

Nevertheless the amplified inductor current downslope at one input of the PWM comparator must not exceed the oscillator ramp slope at the other comparator input. This purpose is reached limiting the gain of the current amplifier.

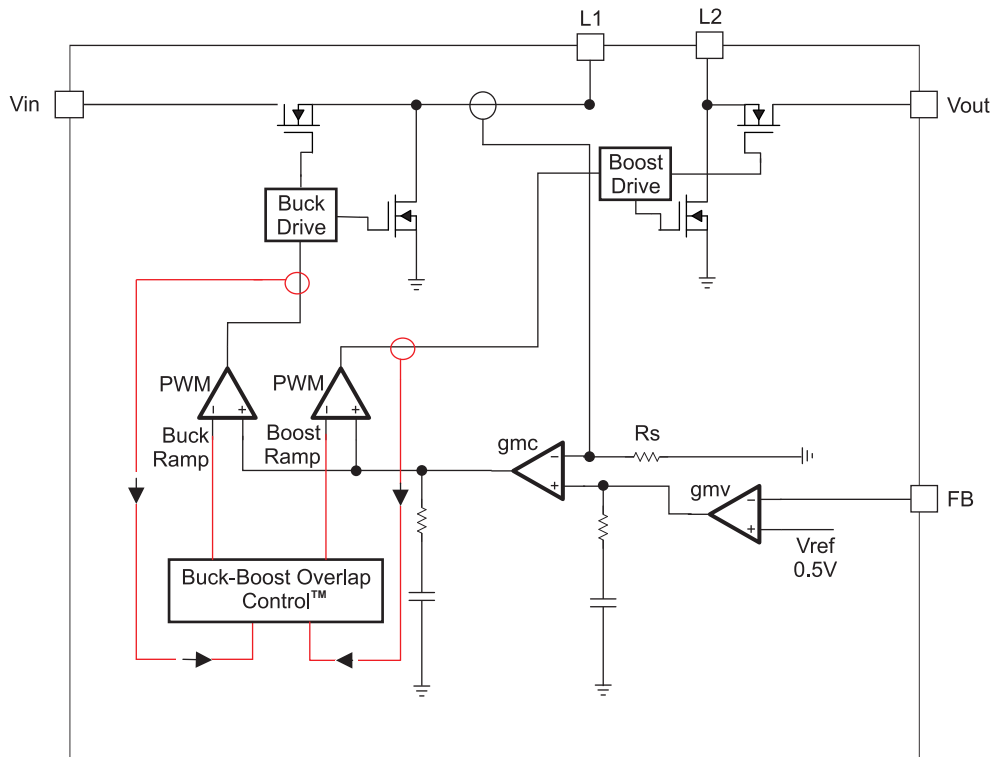


Figure 28. Average Current Mode Control

### Power-save mode and synchronization

The PS/SYNC pin can be used to select different operation modes. Power Save Mode is used to improve efficiency at light load. To enable Power-Save, PS/SYNC must be set low. If PS/SYNC is set low then Power Save Mode is entered when the average inductor current gets lower than about 100mA. At this point the converter operates with reduced switching frequency and with a minimum quiescent current to maintain high efficiency.

During the Power Save Mode, the output voltage is monitored with a comparator by the threshold comp low and comp high. When the device enters Power Save Mode, the converter stops operating and the output voltage drops. The slope of the output voltage depends on the load and the value of output capacitance. As the output voltage falls below the comp low threshold set to 2.5% typical above  $V_{out}$ , the device ramps up the output voltage again, by starting operation using a programmed average inductor current higher than required by the current load condition. Operation can last for one or several pulses. The converter continues these pulses until the comp high threshold, set to typically 3.5% above  $V_{out}$  nominal, is reached and the average inductor current gets lower than about 100mA. When the load increases above the minimum forced inductor current of about 100mA, the device will automatically switch to PWM mode.

The Power Save Mode can be disabled by programming the PS/SYNC high. Connecting a clock signal at PS/SYNC forces the device to synchronize to the connected clock frequency.

Synchronization is done by a PLL to lower and higher frequencies compared to the internal clock. The PLL can also tolerate missing clock pulses without the converter malfunctioning. The PS/SYNC input supports standard logic thresholds.



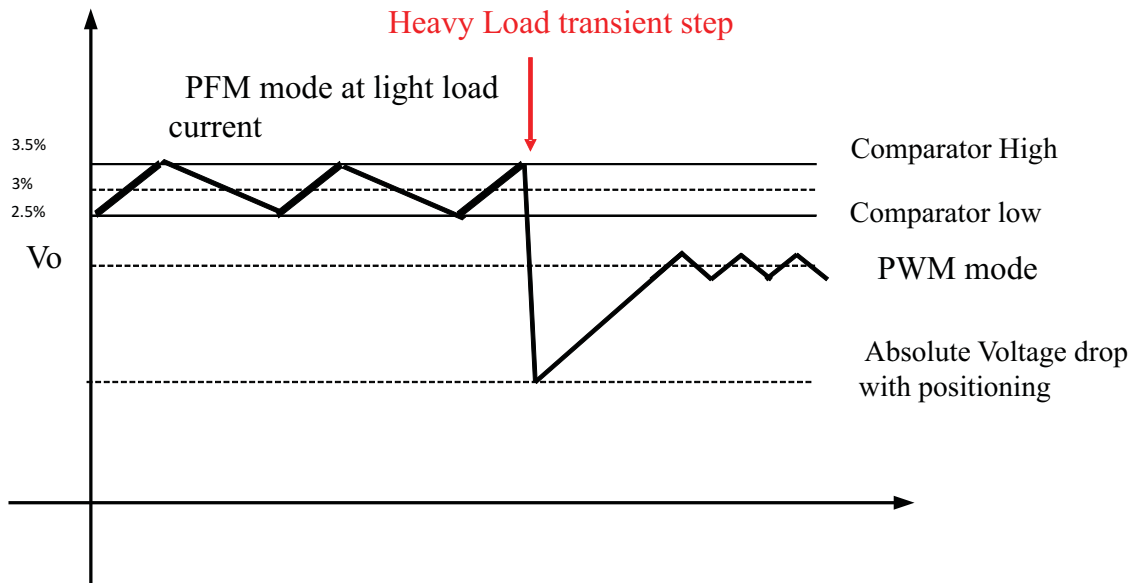


Figure 29. Power-Save Mode Thresholds and Dynamic Voltage Positioning

### Dynamic voltage positioning

As detailed in Figure 29, the output voltage is typically 3% above the nominal output voltage at light load currents, as the device is in Power Save Mode. This gives additional headroom for the voltage drop during a load transient from light load to full load. This allows the converter to operate with a small output capacitor and still have a low absolute voltage drop during heavy load transient changes. See Figure 29 for detailed operation of the Power Save Mode

### Dynamic Current limit

In order to keep the output voltage regulated when the power source becomes weaker the device has implemented a dynamic current limit function. The maximum current allowed through the switch depends on the voltage applied at the input terminal of the TPS6306X. The curve in Figure 30 shows this dependency, and the  $I_{SW}$  versus  $V_{IN}$ . The dynamic current limit has its lowest value when reaching the minimum recommended supply voltage at  $V_{IN}$ .

Given the  $I_{SW}$  value from Figure 30, is then possible to calculate the output current reached in boost mode using Equation 1 and Equation 2 and in buck mode using Equation 3 and Equation 4.

$$\text{Duty Cycle Boost} \quad D = \frac{V_{OUT} - V_{IN}}{V_{OUT}} \quad (1)$$

$$\text{Maximum Output Current Boost} \quad I_{OUT} = \eta \times I_{SW} \times (1 - D) \quad (2)$$

$$\text{Duty Cycle Buck} \quad D = \frac{V_{OUT}}{V_{IN}} \quad (3)$$

$$\text{Maximum Output Current Buck} \quad I_{OUT} = I_{SW} \quad (4)$$

With,

$\eta$  = Estimated converter efficiency (use the number from the efficiency curves or 0.80 as an assumption)

$f$  = Converter switching frequency (typical 2.4 MHz)

$L$  = Selected inductor value

If the die temperature increases above the recommended maximum temperature, the dynamic current limit becomes active. The current limit is reduced with temperature increasing.

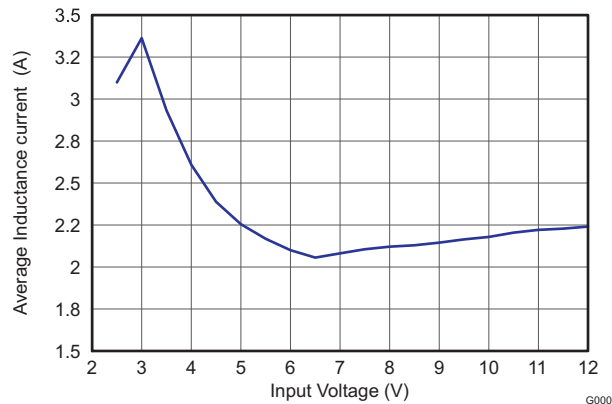


Figure 30. Average Inductance Current versus Input Voltage

### Device Enable

The device is put into operation when EN is set high. It is put into a shutdown mode when EN is set to GND. In shutdown mode, the regulator stops switching, all internal control circuitry is switched off, and the load is disconnected from the input. This means that the output voltage can drop below the input voltage during shutdown. During start-up of the converter, the duty cycle and the peak current are limited in order to avoid high peak currents flowing from the input.

### Power Good

The device has a built in power good function to indicate whether the output voltage is regulated properly. As soon as the average inductor current gets limited to a value below the current the voltage regulator demands for maintaining the output voltage the power good output gets low impedance. The output is open drain, so its logic function can be adjusted to any voltage level the connected logic is using, by connecting a pull up resistor to the supply voltage of the logic. By monitoring the status of the current control loop, the power good output provides the earliest indication possible for an output voltage break down and leaves the connected application a maximum time to safely react.

### Softstart and Short Circuit Protection

After being enabled, the device starts operating. The average current limit ramps up from an initial 400mA following the output voltage increasing. At an output voltage of about 1.2V, the current limit is at its nominal value. If the output voltage does not increase, the current limit will not increase. There is no timer implemented. Thus, the output voltage overshoot at startup, as well as the inrush current, is kept at a minimum. The device ramps up the output voltage in a controlled manner even if a large capacitor is connected at the output. When the output voltage does not increase above 1.2V, the device assumes a short circuit at the output, and keeps the current limit low to protect itself and the application. At a short on the output during operation, the current limit is also kept under 2A typically (minimum average inductance current).

### Overvoltage Protection

If, for any reason, the output voltage is not fed back properly to the input of the voltage amplifier, control of the output voltage will not work anymore. Therefore, overvoltage protection is implemented to avoid the output voltage exceeding critical values for the device and possibly for the system it is supplying. The implemented overvoltage protection circuit monitors the output voltage internally as well. If it reaches the overvoltage threshold, the voltage amplifier regulates the output voltage to this value.

### Undervoltage Lockout

An undervoltage lockout function prevents device start-up if the supply voltage on VIN is lower than approximately its threshold (see the [Electrical Characteristics](#) table). When in operation, the device automatically enters the shutdown mode if the voltage on VIN drops below the undervoltage lockout threshold. The device automatically restarts if the input voltage recovers to the minimum operating input voltage.

### Overtemperature Protection

The device has a built-in temperature sensor which monitors the internal IC temperature. If the temperature exceeds the programmed threshold (see the [Electrical Characteristics](#) table) the device stops operating. As soon as the IC temperature has decreased below the programmed threshold, it starts operating again. There is a built-in hysteresis to avoid unstable operation at IC temperatures at the overtemperature threshold.

## APPLICATION INFORMATION

### DESIGN PROCEDURE

The TPS6306x series of buck-boost converter has internal loop compensation. Therefore, the external L-C filter has to be selected to work with the internal compensation. When selecting the output filter a low limit for the inductor value exists to avoid subharmonic oscillation which could be caused by a far too fast ramp up of the amplified inductor current. For the TPS6306x series, the minimum inductor value should be kept at 1µH. Selecting a larger output capacitor value is less critical because the corner frequency moves to lower frequencies. To simplify this process, [Table 2](#) outlines possible inductor and capacitor value combinations.

**Table 2. Output Filter Selection (Average Inductance current up to 2A)**

INDUCTOR VALUE [µH] <sup>(1)</sup>	OUTPUT CAPACITOR VALUE [µF] <sup>(2)</sup>		
	44	66	100
1.0	√	√ <sup>(3)</sup>	√
1.5	√	√	√

- (1) Inductor tolerance and current de-rating is anticipated. The effective inductance can vary by 20% and –30%.
- (2) Capacitance tolerance and bias voltage de-rating is anticipated. The effective capacitance can vary by 20% and –50%.
- (3) Typical application. Other check mark indicates recommended filter combinations

### Inductor Selection

For high efficiencies, the inductor should have a low dc resistance to minimize conduction losses. Especially at high-switching frequencies the core material has a higher impact on efficiency. When using small chip inductors, the efficiency is reduced mainly due to higher inductor core losses. This needs to be considered when selecting the appropriate inductor. The inductor value determines the inductor ripple current. The larger the inductor value, the smaller the inductor ripple current and the lower the conduction losses of the converter. Conversely, larger inductor values cause a slower load transient response. To avoid saturation of the inductor, with the chosen inductance value, the peak current for the inductor in steady state operation can be calculated. [Equation 1](#) and [Equation 5](#) show how to calculate the peak current  $I_{PEAK}$ . Only the equation which defines the switch current in boost mode is reported because this is providing the highest value of current and represents the critical current value for selecting the right inductor.

$$I_{PEAK} = \frac{I_{out}}{\eta \times (1 - D)} + \frac{V_{in} \times D}{2 \times f \times L} \quad (5)$$

With,

D = Duty Cycle in Boost mode

f = Converter switching frequency (typical 2.4 MHz)

L = Selected inductor value

η = Estimated converter efficiency (use the number from the efficiency curves or 0.80 as an assumption)

**Note:** The calculation must be done for the minimum input voltage which is possible to have in boost mode

Consideration must be given to the load transients and error conditions that can cause higher inductor currents. This must be taken into consideration when selecting an appropriate inductor. See [Table 3](#) for typical inductors.

The size of the inductor can also affect the stability of the feedback loop. In particular the boost transfer function exhibits a right half-plane zero, whose frequency is inverse proportional to the inductor value and the load current. This means higher is the value of inductance and load current more possibilities has the right half plane zero to be moved at lower frequency. This could degrade the phase margin of the feedback loop. It is recommended to choose the inductor's value in order to have the frequency of the right half plane zero >400kHz. The frequency of the RHPZ can be calculated using [Equation 6](#).

$$f_{RHPZ} = \frac{(1 - D)^2 \times V_{out}}{2\pi \times I_{out} \times L} \quad (6)$$

With,

D =Duty Cycle in Boost mode

**Note:** The calculation must be done for the minimum input voltage which is possible to have in boost mode

**Table 3. Inductor Selection**

INDUCTOR VALUE	COMPONENT SUPPLIER	SIZE (LxWxH mm)	Isat/DCR
1 μH	Coilcraft XFL4020-102	4 x 4 x 2.1	5.1A/10.8 mΩ
1 μH	TOKO DEM2815 1226AS-H-1R0N	3 x 3.2 x 1.5	2.7A/27 mΩ
1.5μH	Coilcraft XFL4020-152	4 x 4 x 2.1	4.4A/ 14.40mΩ

## Capacitor selection

### Input Capacitor

At least a 20μF input capacitor is recommended to improve transient behavior of the regulator and EMI behavior of the total power supply circuit. A ceramic capacitor placed as close as possible to the VIN and PGND pins of the IC is recommended.

### Output Capacitor

For the output capacitor, use of a small ceramic capacitors placed as close as possible to the VOUT and PGND pins of the IC is recommended. If, for any reason, the application requires the use of large capacitors which can not be placed close to the IC, use a smaller ceramic capacitor in parallel to the large capacitor. The small capacitor should be placed as close as possible to the VOUT and PGND pins of the IC. The recommended typical output capacitor value is 66μF with a variance as outlined in [Table 2](#).

There is also no upper limit for the output capacitance value. Larger capacitors will cause lower output voltage ripple as well as lower output voltage drop during load transients.

When choosing input and output capacitors, it needs to be kept in mind, that the value of capacitance experiences significant losses from their rated value depending on the operating temperature and the operating DC voltage. It's not uncommon for a small surface mount ceramic capacitor to lose 50% and more of it's rated capacitance. For this reason, it is important to use a larger value of capacitance or a capacitor with higher voltage rating in order to ensure the required capacitance at the full operating voltage.

### Bypass Capacitor

To make sure that the internal control circuits are supplied with a stable low noise supply voltage, a capacitor is connected between VAUX and GND. Using a ceramic capacitor with a value of 0.1μF is recommended. The capacitor needs to be placed close to the VAUX pin. The value of this capacitor should not be higher than 0.22μF.

## Setting the Output Voltage

When the adjustable output voltage version TPS63060 is used, the output voltage is set by the external resistor divider. The resistor divider must be connected between VOUT, FB and GND. When the output voltage is regulated properly, the typical value of the voltage at the FB pin is 500mV. The maximum recommended value for the output voltage is 8V. The current through the resistive divider should be about 100 times greater than the current into the FB pin. The typical current into the FB pin is 0.01μA, and the voltage across the resistor between FB and GND, R<sub>2</sub>, is typically 500 mV. Based on these two values, the recommended value for R<sub>2</sub> should be lower than 500kΩ, in order to set the divider current at 3μA or higher. It is recommended to keep the value for this resistor in the range of 200kΩ. From that, the value of the resistor connected between VOUT and FB, R<sub>1</sub>, depending on the needed output voltage (V<sub>OUT</sub>), can be calculated using [Equation 7](#):

$$R1 = R2 \times \left( \frac{V_{OUT}}{V_{FB}} - 1 \right) \quad (7)$$

A small capacitor C<sub>4</sub>=10pF, in parallel with R<sub>2</sub> needs to be placed when using the Power Save Mode and the adjustable version, to provide filtering and improve the efficiency at light load.

## LAYOUT CONSIDERATIONS

For all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator could show stability problems as well as EMI problems. Therefore, use wide and short traces for the main current path and for the power ground tracks. The input capacitor, output capacitor, and the inductor should be placed as close as possible to the IC. Use a common ground node for power ground and a different one for control ground to minimize the effects of ground noise. Connect these ground nodes at any place close to one of the ground pins of the IC.

The feedback divider should be placed as close as possible to the control ground pin of the IC. To lay out the control ground, short traces are recommended as well, separation from the power ground traces. This avoids ground shift problems, which can occur due to superimposition of power ground current and control ground current.

## THERMAL INFORMATION

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

Three basic approaches for enhancing thermal performance are listed below.

- Improving the power dissipation capability of the PCB design
- Improving the thermal coupling of the component to the PCB by soldering the PowerPAD™
- Introducing airflow in the system

For more details on how to use the thermal parameters in the dissipation ratings table please check the [Thermal Characteristics Application Note \(SZZA017\)](#) and the [IC Package Thermal Metrics Application Note \(SPRA953\)](#).

TYPICAL APPLICATION

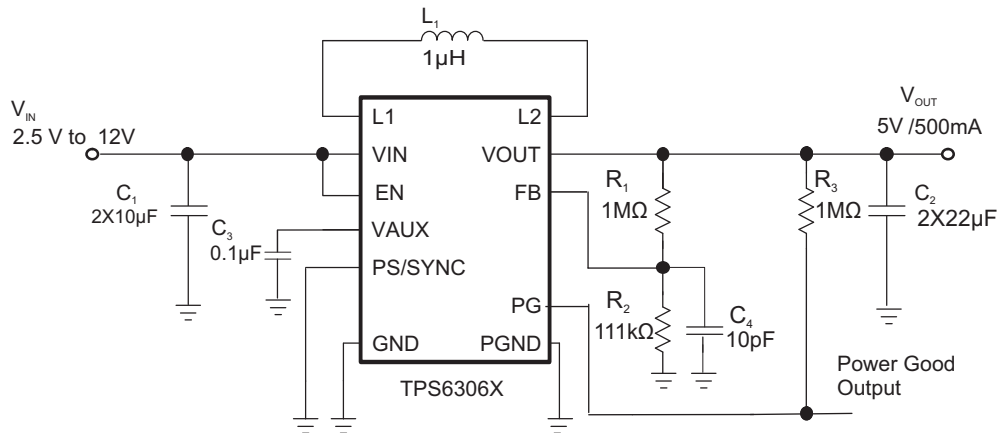


Figure 31. 5V and 500mA from 1 or 2 cell Li-Ion

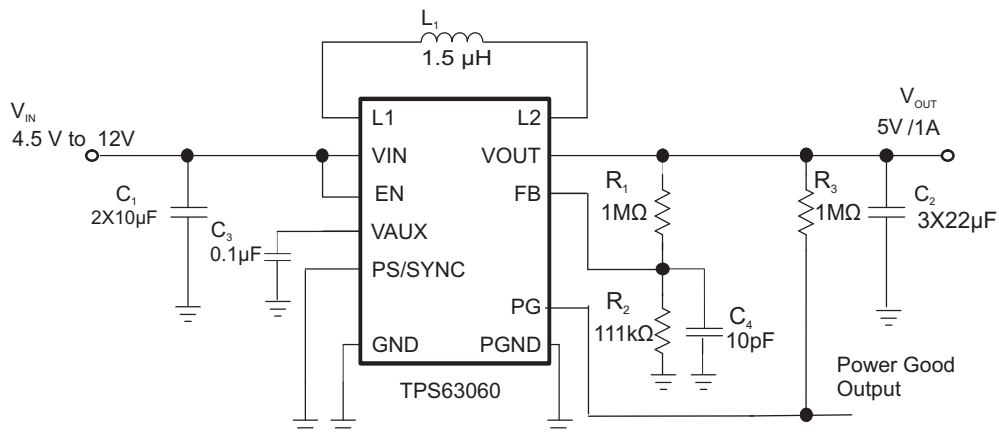


Figure 32. 5V and 1A from Input Voltage up to 12V

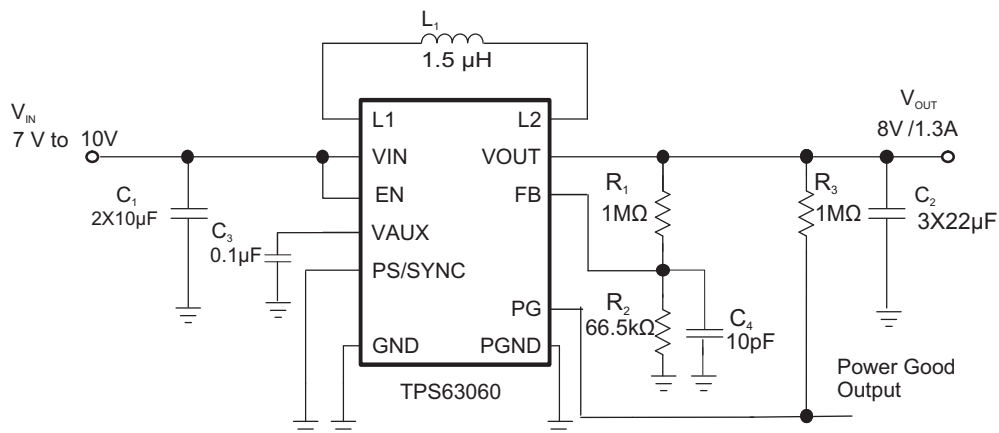


Figure 33. 8V and 1.3A from 2 cell Li-Ion

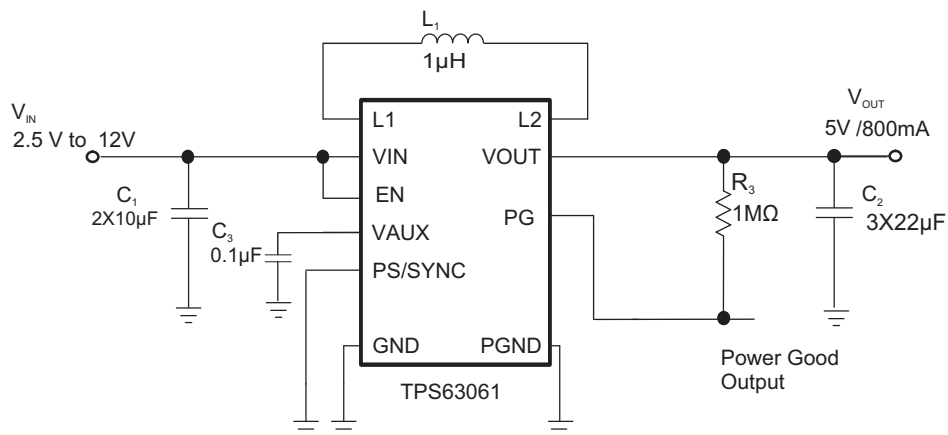


Figure 34. TPS63061 5V Fixed Output Voltage



**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS63060DSCR	ACTIVE	WSON	DSC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	QUJ	<a href="#">Samples</a>
TPS63060DSCT	ACTIVE	WSON	DSC	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	QUJ	<a href="#">Samples</a>
TPS63061DSCR	ACTIVE	WSON	DSC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	QUK	<a href="#">Samples</a>
TPS63061DSCT	ACTIVE	WSON	DSC	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	QUK	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**OTHER QUALIFIED VERSIONS OF TPS63060 :**

- Enhanced Product: [TPS63060-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS63060DSCR	WSON	DSC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS63060DSCT	WSON	DSC	10	250	180.0	12.5	3.3	3.3	1.1	8.0	12.0	Q2
TPS63060DSCT	WSON	DSC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS63061DSCR	WSON	DSC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS63061DSCR	WSON	DSC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS63061DSCT	WSON	DSC	10	250	180.0	12.5	3.3	3.3	1.1	8.0	12.0	Q2
TPS63061DSCT	WSON	DSC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

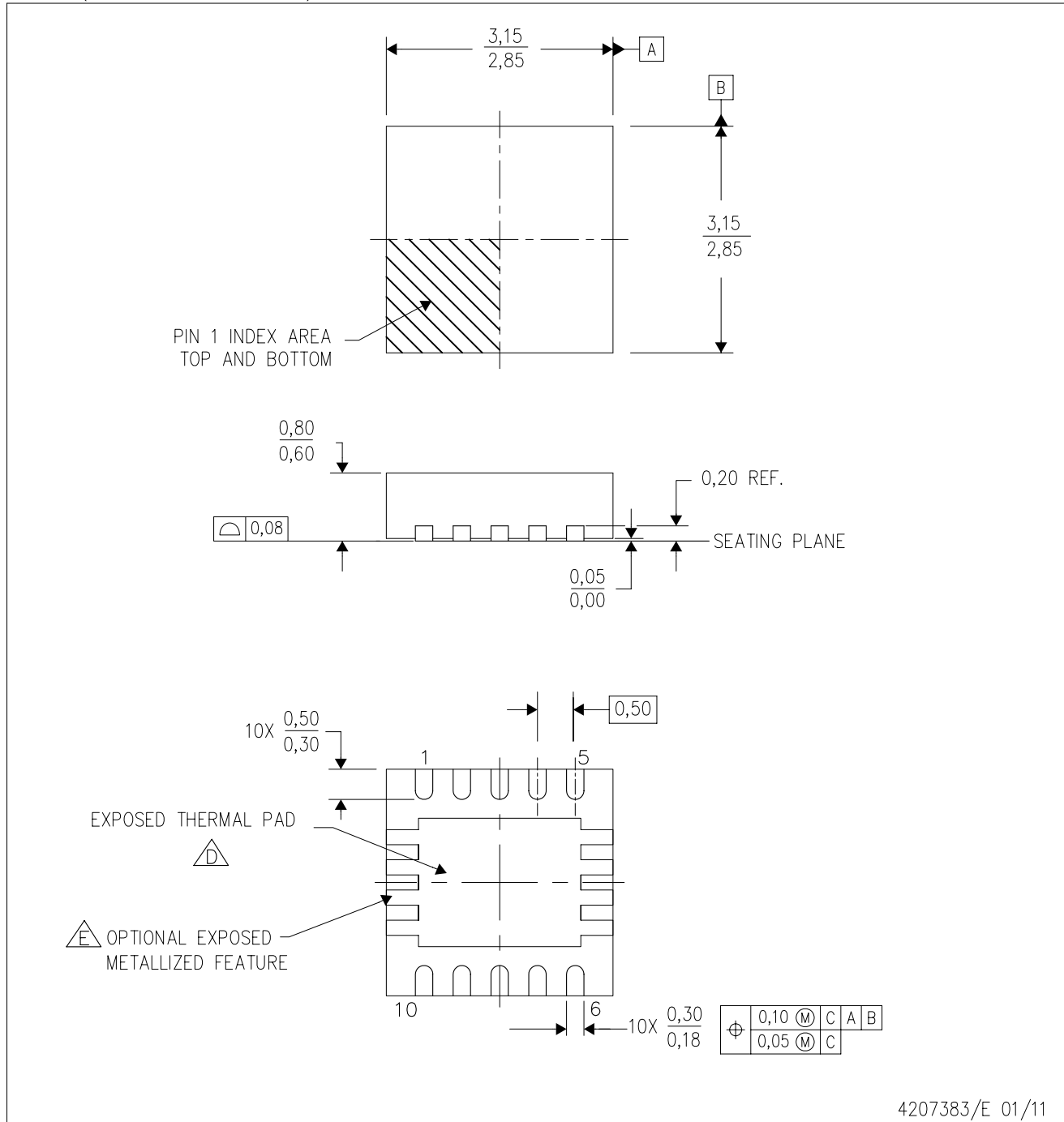
**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS63060DSCR	WSON	DSC	10	3000	338.0	355.0	50.0
TPS63060DSC T	WSON	DSC	10	250	205.0	200.0	33.0
TPS63060DSC T	WSON	DSC	10	250	210.0	185.0	35.0
TPS63061DSCR	WSON	DSC	10	3000	338.0	355.0	50.0
TPS63061DSCR	WSON	DSC	10	3000	367.0	367.0	35.0
TPS63061DSC T	WSON	DSC	10	250	205.0	200.0	33.0
TPS63061DSC T	WSON	DSC	10	250	210.0	185.0	35.0

DSC (S-PWSON-N10)

PLASTIC SMALL OUTLINE NO-LEAD



4207383/E 01/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Small Outline No-Lead (SON) package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - See the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.

# THERMAL PAD MECHANICAL DATA

DSC (S-PWSON-N10)

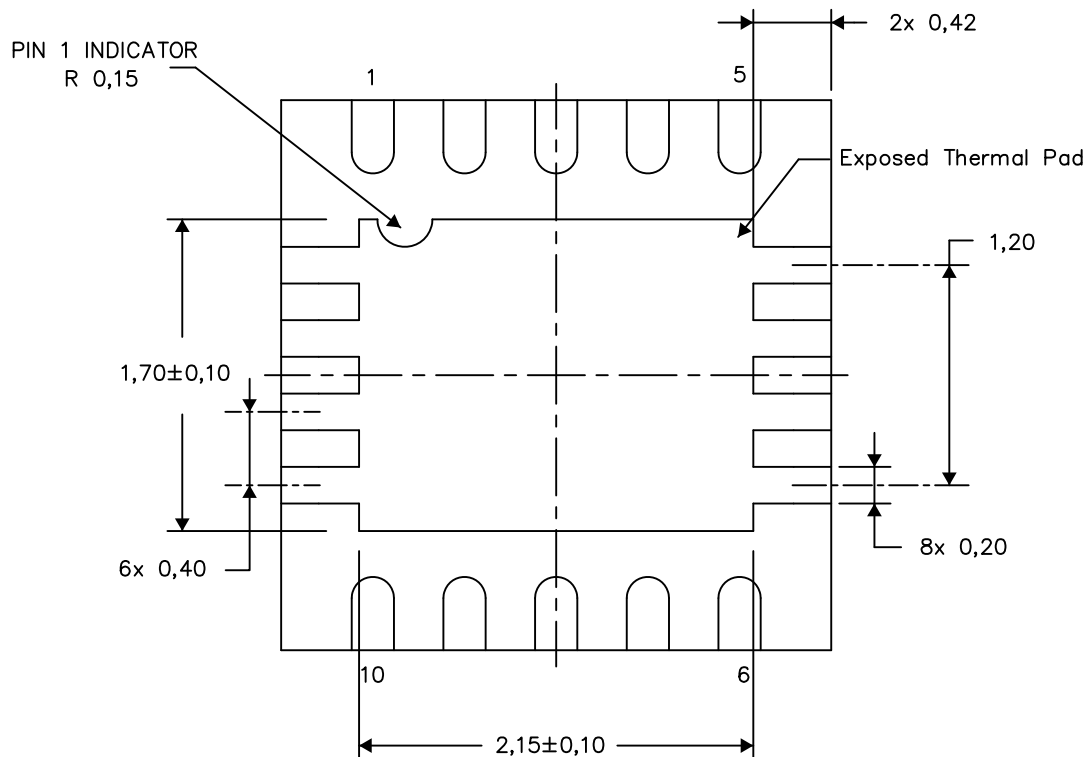
PLASTIC SMALL OUTLINE NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

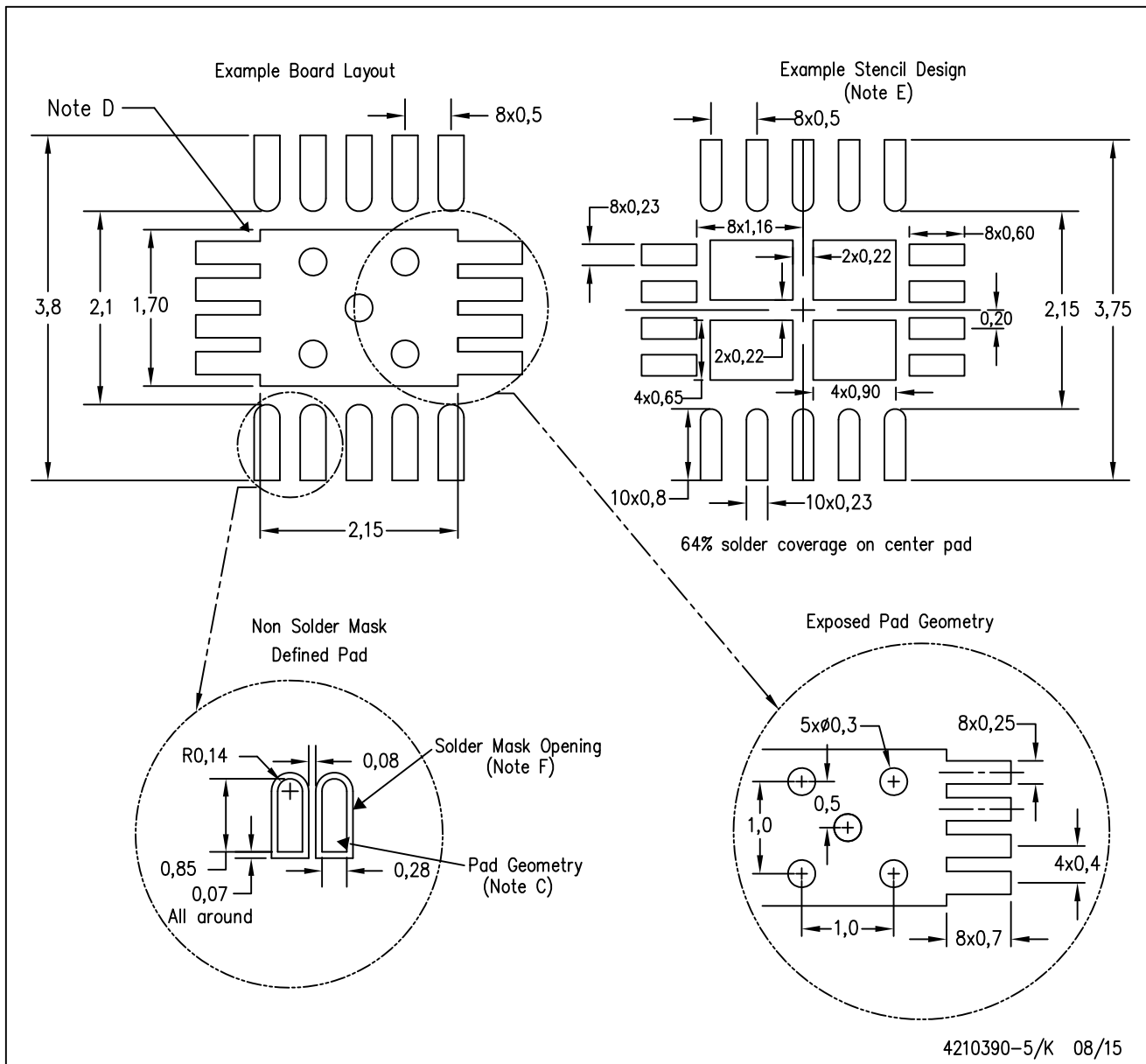
Exposed Thermal Pad Dimensions

4210391-5/Q 08/15

NOTE: A. All linear dimensions are in millimeters

DSC (S-PWSON-N10)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

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邮寄地址：上海市浦东新区世纪大道 1568 号中建大厦 32 楼，邮政编码：200122  
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